## NSN 5961-01-331-6377

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-6377 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.260 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.080 inches and 0.120 inches **Function For Which Designed:** Rectifier **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage, peak total value and 28.0 reverse voltage, total rms **Current Rating Per Characteristic:** 1.00 amperes collector current, dc absolute and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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